

RF Power MOSFET Transistor 100W, 100-500 MHz, 28V

Rev. V1

Features

- N-channel enhancement mode device
- DMOS structure
- Lower capacitances for broadband operation
- · High saturated output power
- Lower noise figure than competitive devices

ABSOLUTE MAXIMUM RATINGS AT 25° C

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V_{DS}	65	٧
Gate-Source Voltage	V_{GS}	20	V
Drain-Source Current	I _{DS}	12*	Α
Power Dissipation	P_D	250	W
Junction Temperature	TJ	200	°C
Storage Temperature	T_{STG}	-55 to +150	°C
Thermal Resistance	θ_{JC}	0.7	°C/W

TYPICAL DEVICE IMPEDANCES

F (MHz)	Z _{IN} (Ω)	Z _{LOAD} (Ω)		
100	4.5-j6.0	14.5+j0.5		
300	2.25-j1.75	7.5j1.0		
500	1.5+j5.5	3.5+j3.5		
V _{DD} =28V, I _{DQ} =600 Ma, P _{OUT} =100.0 W				

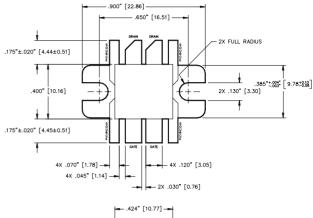
 $Z_{\mbox{\scriptsize IN}}$ is the series equivalent input impedance of the device from gate to gate.

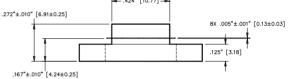
 $Z_{\text{\tiny LOAD}}$ is the optimum series equivalent load impedance as measured from drain to drain.

FLECTRICAL CHARACTERISTICS AT 25°C

Parameter	Symbol	Min	Max	Units	Test Conditions
Drain-Source Breakdown Voltage	BV _{DSS}	65	-	V	V _{GS} = 0.0 V , I _{DS} = 15.0 mA
Drain-Source Leakage Current	I _{DSS}	-	3.0	mA	V _{GS} = 28.0 V , V _{GS} = 0.0 V
Gate-Source Leakage Current	I _{GSS}	-	3.0	μA	V _{GS} = 20.0 V , V _{DS} = 0.0 V
Gate Threshold Voltage	$V_{GS(TH)}$	2.0	6.0	V	V _{DS} = 10.0 V , I _{DS} = 300.0 mA
Forward Transconductance	G _M	1.5	-	S	V_{DS} = 10.0 V , I_{DS} 3000.0 mA , Δ V_{GS} = 1.0V, 80 μ s Pulse
Input Capacitance	C _{ISS}	-	135	pF	V _{DS} = 28.0 V , F = 1.0 MHz
Output Capacitance	Coss	-	90	pF	V _{DS} = 28.0 V , F = 1.0 MHz
Reverse Capacitance	C _{RSS}	-	24	pF	V _{DS} = 28.0 V , F = 1.0 MHz
Power Gain	G _P	10	-	dB	V _{DD} = 28.0 V, I _{DQ} = 600.0 mA, P _{OUT} = 100.0 W F =500 MHz
Drain Efficiency	ŋ _D	50	-	%	V _{DD} = 28.0 V, I _{DQ} = 600.0 mA, P _{OUT} = 100.0 W F =500 MHz
Return Loss	RL	10	-	dB	V _{DD} = 28.0 V, I _{DQ} = 600.0 mA, P _{OUT} = 100.0 W F =500 MHz
Load Mismatch Tolerance	VSWR-T	-	30:1	-	$V_{DD} = 28.0 \text{ V}, I_{DQ} = 600.0 \text{ mA}, P_{OUT} = 100.0 \text{ W F} = 500 \text{ MHz}$

^{*}Per side





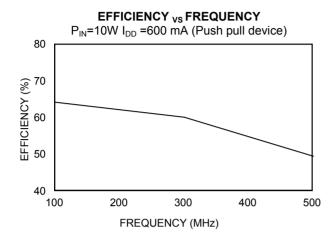
UNLESS OTHERWISE NOTED, TOLERANCES ARE INCHES ±.005" [MILLIMETERS ±0.13mm]

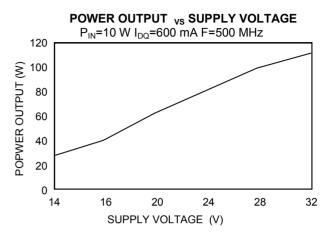


RF Power MOSFET Transistor 100W, 100-500 MHz, 28V

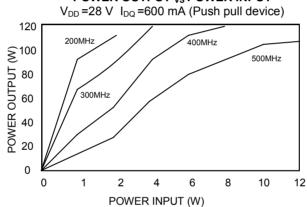
Rev. V1

Typical Broadband Performance Curves





POWER OUTPUT _{VS} POWER INPUT

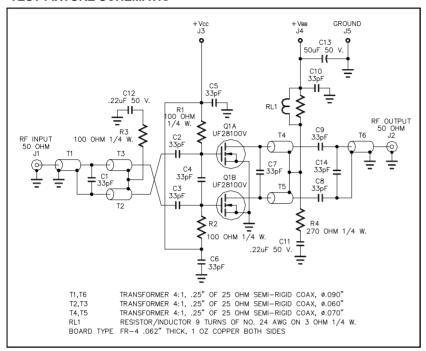




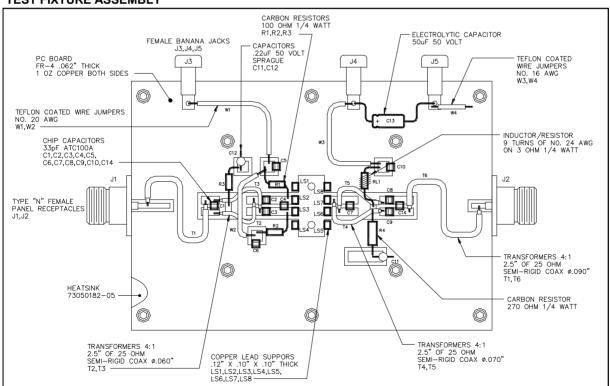
RF Power MOSFET Transistor 100W, 100-500 MHz, 28V

Rev. V1

TEST FIXTURE SCHEMATIC



TEST FIXTURE ASSEMBLY



UF28100V



RF Power MOSFET Transistor 100W, 100-500 MHz, 28V

Rev. V1

M/A-COM Technology Solutions Inc. All rights reserved.

Information in this document is provided in connection with M/A-COM Technology Solutions Inc ("MACOM") products. These materials are provided by MACOM as a service to its customers and may be used for informational purposes only. Except as provided in MACOM's Terms and Conditions of Sale for such products or in any separate agreement related to this document, MACOM assumes no liability whatsoever. MACOM assumes no responsibility for errors or omissions in these materials. MACOM may make changes to specifications and product descriptions at any time, without notice. MACOM makes no commitment to update the information and shall have no responsibility whatsoever for conflicts or incompatibilities arising from future changes to its specifications and product descriptions. No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document.

THESE MATERIALS ARE PROVIDED "AS IS" WITHOUT WARRANTY OF ANY KIND, EITHER EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, CONSEQUENTIAL OR INCIDENTAL DAMAGES, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT. MACOM FURTHER DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. MACOM SHALL NOT BE LIABLE FOR ANY SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS, WHICH MAY RESULT FROM THE USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.